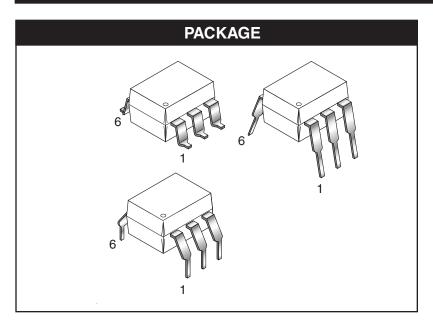
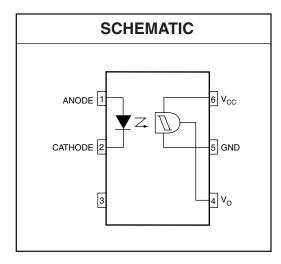


H11L1M H11L2M H11L3M





DESCRIPTION

The H11LXM series has a high speed integrated circuit detector optically coupled to a gallium-arsenide infrared emitting diode. The output incorporates a Schmitt trigger, which provides hysteresis for noise immunity and pulse shaping. The detector circuit is optimized for simplicity of operation and utilizes an open collector output for maximum application flexibility.

FEATURES

- High data rate, 1 MHz typical (NRZ)
- Free from latch up and oscilliation throughout voltage and temperature ranges.
- · Microprocessor compatible drive
- Logic compatible output sinks 16 mA at 0.4 V maximum
- · Guaranteed on/off threshold hysteresis
- Wide supply voltage capability, compatible with all popular logic systems
- Underwriters Laboratory (UL) recognized—file #E90700, Volume 2
- VDE recognized File#102497 Add option V (e.g., H11LIVM)

APPLICATIONS

- Logic to logic isolator
- Programmable current level sensor
- Line receiver—eliminate noise and transient problems
- A.C. to TTL conversion—square wave shaping
- · Digital programming of power supplies
- Interfaces computers with peripherals

Truth Table

Input	Output
Н	L
L	Н



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ABSOLUTE MAXIMUM RATINGS				
Parameters	Symbol	Device	Value	Units
TOTAL DEVICE				
Storage Temperature	T _{STG}	All	-55 to +150	°C
Operating Temperature	T _{OPR}	All	-40 to +85	°C
Lead Solder Temperature	T _{SOL}	All	260 for 10 sec	°C
Total Device Power Dissipation @ 25°C	P _D	All	250	mW
Derate Above 25°C		All	2.94	mW/°C
EMITTER				
Continuous Forward Current	I _F	All	60	mA
Reverse Voltage	V _R	All	6	V
Forward Current - Peak (1 µs pulse, 300 pps)	I _F (pk)	All	3.0	Α
LED Power Dissipation 25°C Ambient	ь	A II	120	mW
Derate Linearly From 25°C	P _D	All	1.41	mW/°C
DETECTOR				
Detector Power Dissipation @ 25°C	Ь В	All	150	mW
Derate Linearly from 25°C	P _D	All	2.0	mW/°C
V ₄₅ Allowed Range	V _O	All	0 to 16	V
V ₆₅ Allowed Range	V _{CC}	All	3 to 16	V
I ₄ Output Current	Io	All	50	mA

ELECTRICAL CHARACTERISTICS (T _A = 25°C Unless otherwise specified.)							
INDIVIDUAL COMPONENT CHARACTERISTICS							
Parameters	Test Conditions	Symbol	Device	Min	Тур	Max	Units
EMITTER							
Innut Converd Valtons	I _F = 10 mA	V _F	All		1.2	1.5	V
Input Forward Voltage	I _F = 0.3 mA			0.75	1.0		V
Reverse Current	V _R = 3 V	I _R	All			10	μΑ
Capacitance	V = 0, f = 1.0 MHz	СЈ	All			100	pF
DETECTOR							
Operating Voltage Range		V _{CC}	All	3		15	V
Supply Current	I _F = 0, V _{CC} = 5V	I _{CC(off)}	All		1.6	5.0	mA
Output Current, High	$I_F = 0, V_{CC} = V_O = 15V$	I _{OH}	All			100	μΑ



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ISOLATION CHARACTERISTICS						
Parameters	Test Conditions	Symbol	Min	Тур	Max	Units
Input-Output Isolation Voltage	t=1 sec.	V _{ISO}	7500			V _{PEAK}
Isolation Capacitance	$V_{I-O} = 0V$, $f = 1 MHz$	C _{ISO}		0.4	0.6	pF
Isolation Resistance	V _{I-O} = ±500 VDC	R _{ISO}	10 ¹¹			Ω

TRANSFER CHARAC	CTERISTICS						
DC Characteristics	Test Conditions	Symbol	Device	Min	Тур	Max	Units
Supply Current	I _F = 10mA, V _{CC} = 5V	I _{CC(on)}	All		1.6	5.0	mA
Output Voltage, low	R_L =270 Ω , V_{CC} =5 V , I_F = $I_{F(on)}$ max.	V _{OL}	All		0.2	0.4	V
			H11L1M			1.6	
Turn-On Threshold Current	$R_L=270\Omega$, $V_{CC}=5V$	I _{F(on)} *	H11L2M			10.0	mA
			H11L3M			5.0	1
Turn-Off Threshold Current	$R_L=270\Omega$, $V_{CC}=5V$	I _{F(off)}	All	0.3	1.0		mA
Hysteresis Ratio	$R_L=270\Omega$, $V_{CC}=5V$	I _{F(off)} /I _{F(on)}	All	0.50	0.75	0.90	
AC Characteristics	Test Conditions	Symbol	Device	Min	Тур	Max	Units
SWITCHING SPEED							
	$R_L=270\Omega$, $V_{CC}=5V$, $I_F=I_{F(on)}$, $T_A=25^{\circ}C$	t _{on}	All		1.0		
Turn-On time					0.65		μs
						4	
	$R_L=270\Omega$, $V_{CC}=5V$, $I_F=I_{F(on)}$, $I_A=25^{\circ}C$	t _f	All		0.1		
Fall Time					.05		μs
					0.1		
	$R_L=270\Omega$, $V_{CC}=5V$, $I_F=I_{F(on)}$, $I_A=25^{\circ}C$	t _{off}	All		2.0		
Turn-Off Time					1.2		μs
						4	
Rise time	$R_L=270\Omega$, $V_{CC}=5V$, $I_F=I_{F(on)}$, $I_A=25^{\circ}C$	t _r	All		0.1		
					0.07		μs
					0.1		
Data Rate			All		1.0		MHz

NOTE:

^{*}Maximum $I_{F(ON)}$ is the maximum current required to trigger the output. For example, a 1.6mA maximum trigger current would require the LED to be driven at a current greater than 1.6mA to guarantee the device will turn on. A 10% guard band is recommended to account for degradation of the LED over its lifetime. The maximum allowable LED drive current is 60mA.



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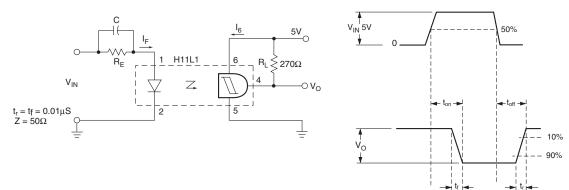
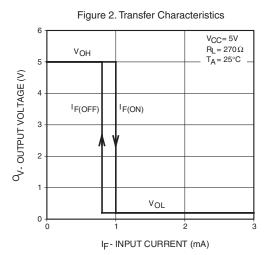
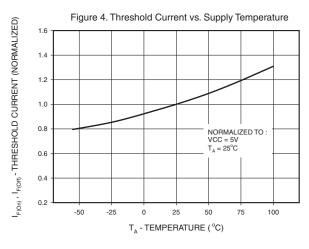
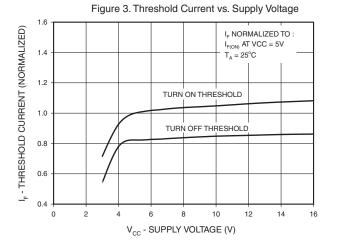


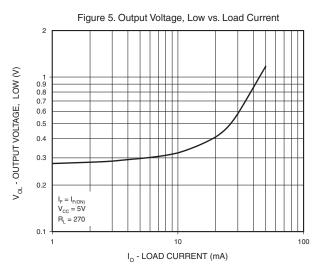
Figure 1. Switching Test Circuit and Waveforms

TYPICAL PERFORMANCE CURVES





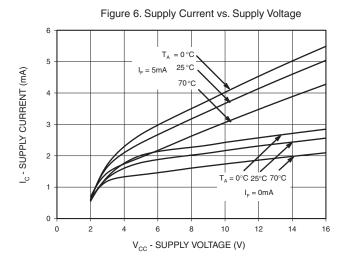


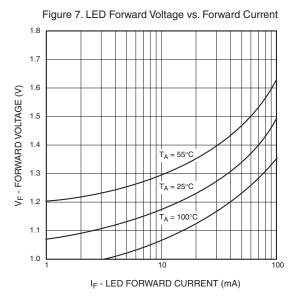




H11L1M H11L2M H11L3M

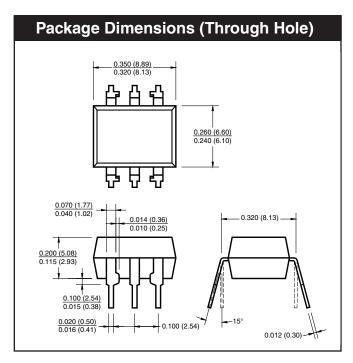
TYPICAL PERFORMANCE CURVES

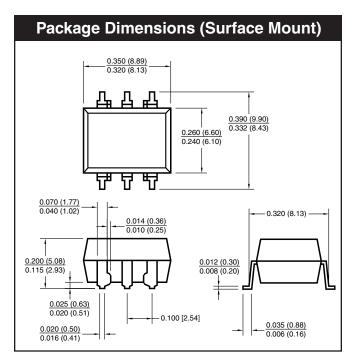


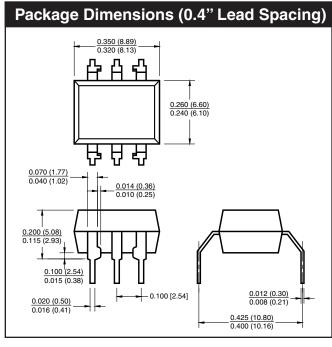


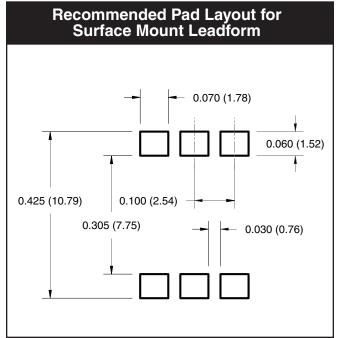


H11L1M H11L2M H11L3M









NOTE

All dimensions are in inches (millimeters)

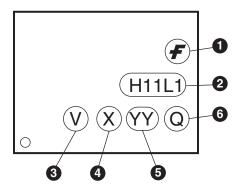


H11L1M H11L2M H11L3M

ORDERING INFORMATION

Option/Order Entry Identifier	Description
S	Surface Mount Lead Bend
SR2	Surface Mount; Tape and reel
Т	0.4" Lead Spacing
V	VDE 0884
TV	VDE 0884, 0.4" Lead Spacing
SV	VDE 0884, Surface Mount
SR2V	VDE 0884, Surface Mount, Tape & Reel

MARKING INFORMATION

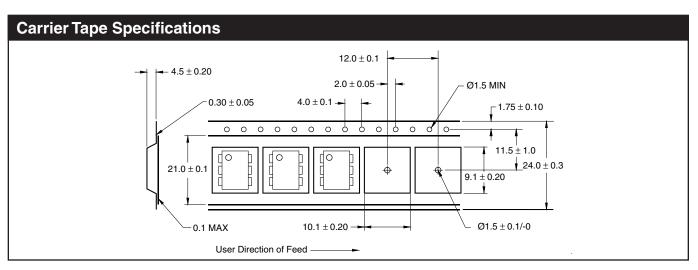


Definitions				
1	Fairchild logo			
2	Device number			
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)			
4	One digit year code, e.g., '3'			
5	Two digit work week ranging from '01' to '53'			
6	Assembly package code			

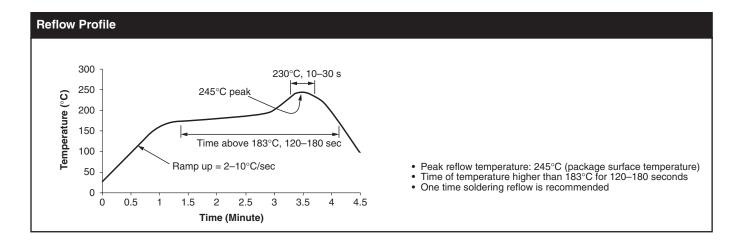
^{*}Note – 'V' option parts marked with date code '325' or earlier are marked in portrait format.



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NOTEAll dimensions are in inches (millimeters)





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